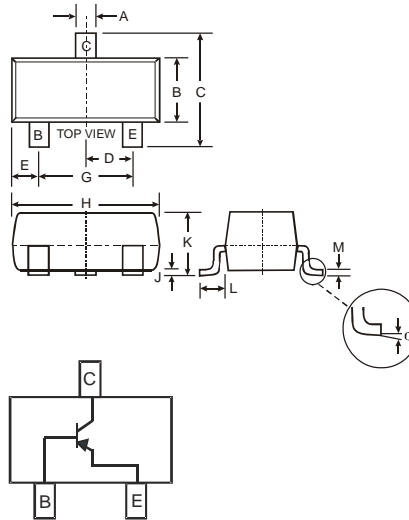


Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (MMBT2222A)
- Ideal for Low Power Amplification and Switching
- **Lead Free/RoHS Compliant (Note 2)**

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking (See Page 4): K2F
- Ordering & Date Code Information: See Page 4
- Weight: 0.008 grams (approximate)



| SOT-23 | | |
|----------------------|-------|-------|
| Dim | Min | Max |
| A | 0.37 | 0.51 |
| B | 1.20 | 1.40 |
| C | 2.30 | 2.50 |
| D | 0.89 | 1.03 |
| E | 0.45 | 0.60 |
| G | 1.78 | 2.05 |
| H | 2.80 | 3.00 |
| J | 0.013 | 0.10 |
| K | 0.903 | 1.10 |
| L | 0.45 | 0.61 |
| M | 0.085 | 0.180 |
| α | 0° | 8° |
| All Dimensions in mm | | |

Maximum Ratings @T_A = 25°C unless otherwise specified

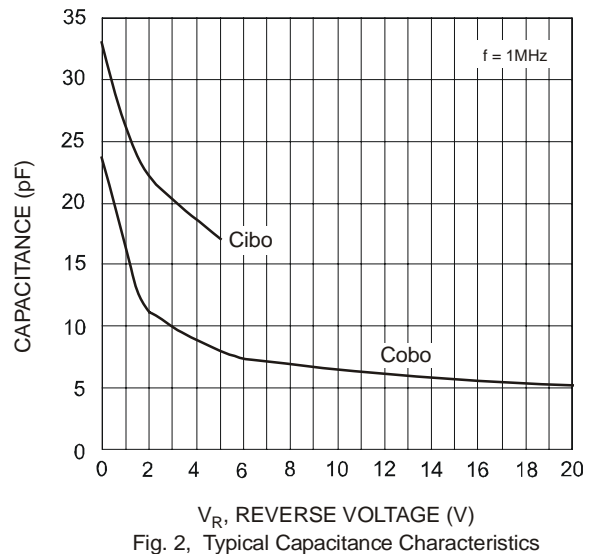
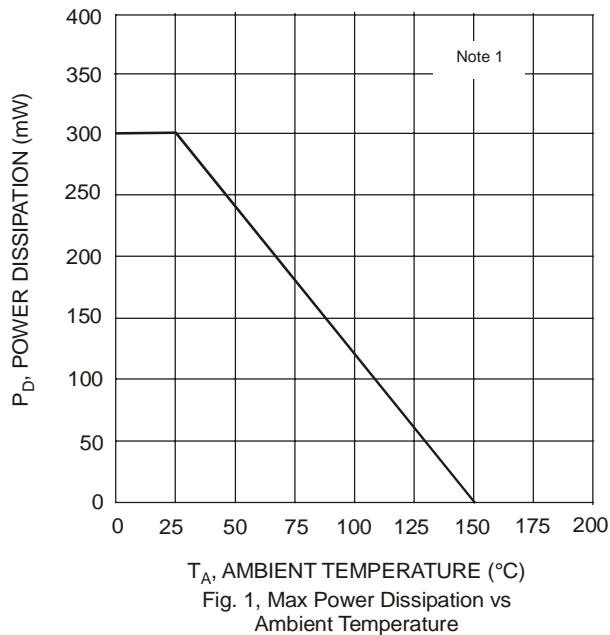
| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Collector-Base Voltage | V _{CB0} | -60 | V |
| Collector-Emitter Voltage | V _{CEO} | -60 | V |
| Emitter-Base Voltage | V _{EBO} | -5.0 | V |
| Collector Current - Continuous (Note 1) | I _C | -600 | mA |
| Peak Collector Current | I _{CM} | -800 | mA |
| Power Dissipation (Note 1) | P _d | 300 | mW |
| Thermal Resistance, Junction to Ambient (Note 1) | R _{θJA} | 417 | °C/W |
| Operating and Storage and Temperature Range | T _j , T _{STG} | -55 to +150 | °C |

- Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
2. No purposefully added lead.

Electrical Characteristics @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Min | Max | Unit | Test Condition |
|--------------------------------------|----------------------|-------------------------------|-------------------------|----------|--|
| OFF CHARACTERISTICS (Note 3) | | | | | |
| Collector-Base Breakdown Voltage | V _{(BR)CBO} | -60 | — | V | I _C = -10μA, I _E = 0 |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | -60 | — | V | I _C = -10mA, I _B = 0 |
| Emitter-Base Breakdown Voltage | V _{(BR)EBO} | -5.0 | — | V | I _E = -10μA, I _C = 0 |
| Collector Cutoff Current | I _{CBO} | — | -10 | nA μA | V _{CB} = -50V, I _E = 0 V _{CB} = -50V, I _E = 0, T _A = 125°C |
| Collector Cutoff Current | I _{CEX} | — | -50 | nA | V _{CE} = -30V, V _{EB(OFF)} = -0.5V |
| Base Cutoff Current | I _{BL} | — | -50 | nA | V _{CE} = -30V, V _{EB(OFF)} = -0.5V |
| ON CHARACTERISTICS (Note 3) | | | | | |
| DC Current Gain | h _{FE} | 75 100 100 100 50 | — — — 300 — | — | I _C = -100μA, V _{CE} = -10V I _C = -1.0mA, V _{CE} = -10V I _C = -10mA, V _{CE} = -10V I _C = -150mA, V _{CE} = -10V I _C = -500mA, V _{CE} = -10V |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | — | -0.4 -1.6 | V | I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | — | -1.3 -2.6 | V | I _C = 150mA, I _B = 15mA I _C = 500mA, I _B = 50mA |
| SMALL SIGNAL CHARACTERISTICS | | | | | |
| Output Capacitance | C _{obo} | — | 8.0 | pF | V _{CB} = -10V, f = 1.0MHz, I _E = 0 |
| Input Capacitance | C _{ibo} | — | 30 | pF | V _{EB} = -2.0V, f = 1.0MHz, I _C = 0 |
| Current Gain-Bandwidth Product | f _T | 200 | — | MHz | V _{CE} = -20V, I _C = -50mA, f = 100MHz |
| SWITCHING CHARACTERISTICS | | | | | |
| Turn-On Time | t _{off} | — | 45 | ns | V _{CC} = -30V, I _C = -150mA, I _{B1} = -15mA |
| Delay Time | t _d | — | 10 | ns | |
| Rise Time | t _r | — | 40 | ns | |
| Turn-Off Time | t _{off} | — | 100 | ns | V _{CC} = -6.0V, I _C = -150mA, I _{B1} = I _{B2} = -15mA |
| Storage Time | t _s | — | 80 | ns | |
| Fall Time | t _f | — | 30 | ns | |

Notes: 3. Short duration pulse test used to minimize self-heating effect.



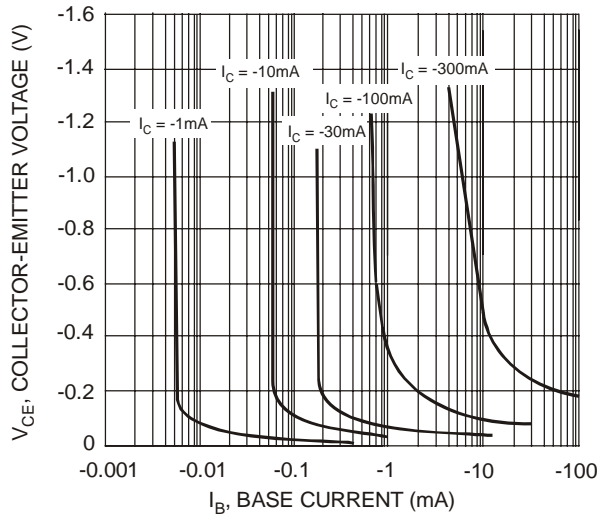


Fig. 3, Typical Collector Saturation Region

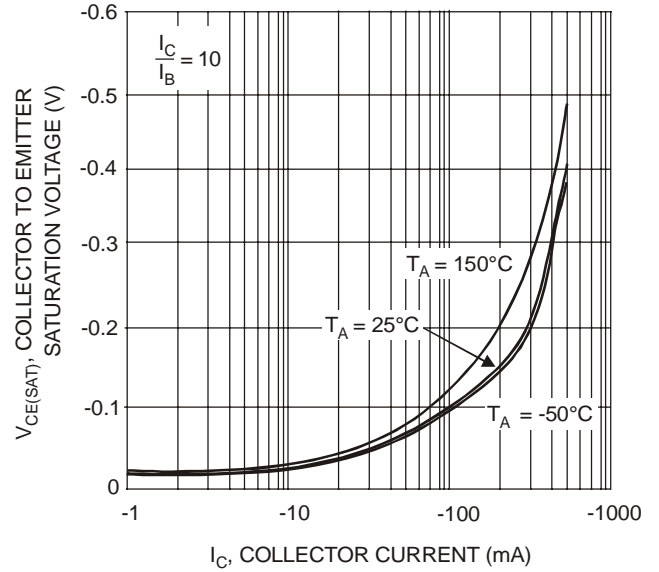


Fig. 4, Collector-Emitter Saturation Voltage vs. Collector Current

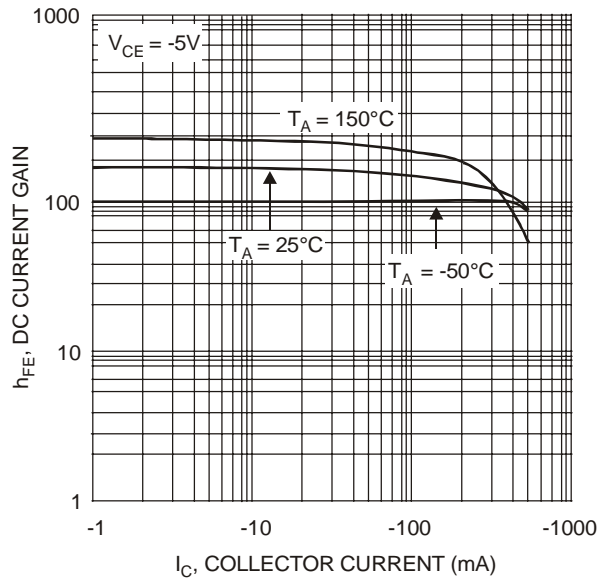


Fig. 5, DC Current Gain vs Collector Current

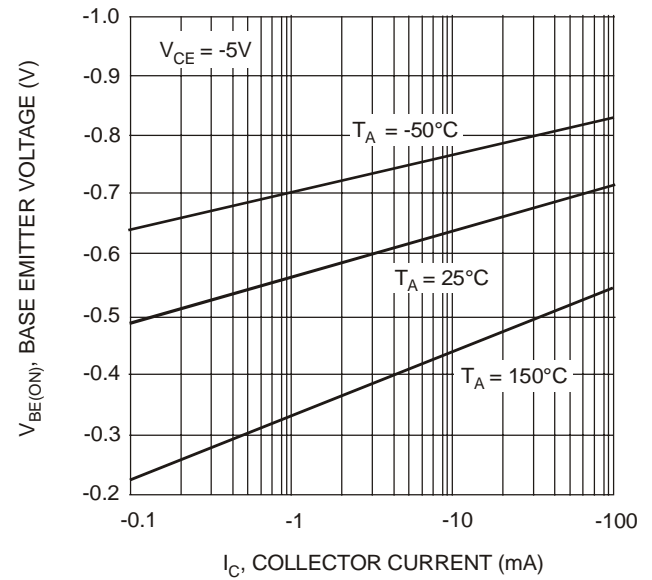


Fig. 6, Base-Emitter Voltage vs. Collector Current

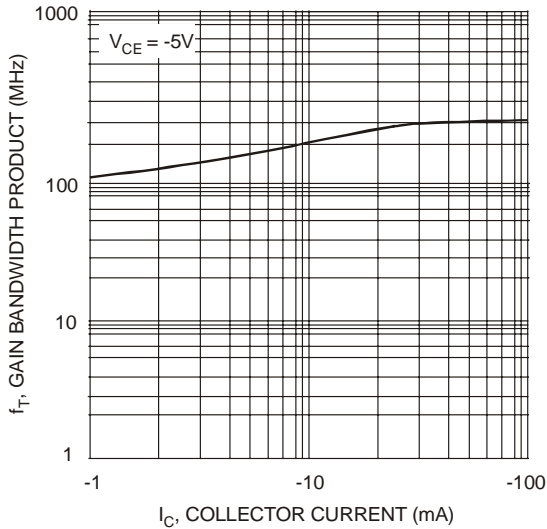


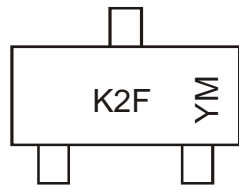
Fig. 7, Gain Bandwidth Product vs. Collector Current

Ordering Information (Note 4)

| Device | Packaging | Shipping |
|---------------|-----------|------------------|
| MMBT2907A-7-F | SOT-23 | 3000/Tape & Reel |

Notes: 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



K2F = Product Type Marking Code
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

| Year | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 |
|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|
| Code | J | K | L | M | N | P | R | S | T | U | V | W | X | Y | Z |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

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